
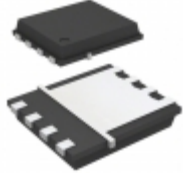
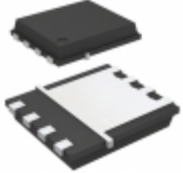
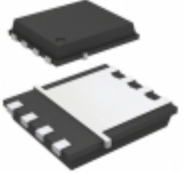
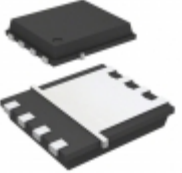



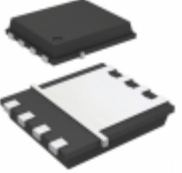
	<h2>FDMS8026S</h2>
	<p>Hersteller-Teilenummer: FDMS8026S</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V POWER56</p> <p>Datenblätter:  FDMS8026S.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 54134 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMS8026S
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V POWER56
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	54134 pcs Stock
Hersteller Standard Vorlaufzeit	39 Weeks
detaillierte Beschreibung	N-Channel 30V 19A (Ta), 22A (Tc) 2.5W (Ta), 41W
Serie	PowerTrench®, SyncFET™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-PQFN (5x6)
Verlustleistung (max)	2.5W (Ta), 41W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19A (Ta), 22A (Tc)
Rds On (Max) @ Id, Vgs	4.3 mOhm @ 19A, 10V
VGS (th) (Max) @ Id	3V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	37nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2280pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FDMS8026STR


















































FDMS8026S ist neu im Original. Suche FDMS8026S Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMS8026S AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FDMS8026S: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDMS8027S Fairchild/ON Semiconductor MOSFET N-CH 30V POWER56</p>	 <p>FDMS8027S AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V POWER56</p>	 <p>FDMS8023S Fairchild/ON Semiconductor MOSFET N-CH 30V POWER56</p>	 <p>FDMS8026S Fairchild/ON Semiconductor MOSFET N-CH 30V POWER56</p>
 <p>FDMS8050 FAI FAI QFN</p>	 <p>FDMS8025AS FAIRCHILD FDMS8025AS FAIRCHILD</p>	 <p>FDMS8050 AMI Semiconductor / ON Semiconductor MOSFET N-CHANNEL 30V 55A 8PQFN</p>	 <p>FDMS8027S FDK America MOSFET N-CH 30V POWER56</p>

heiße Teile

Mehr

 FDMS7680	 FDMS7680	 FDMS7682	 FDMS7682	 FDMS7692
 FDMS7692	 FDMS7692A	 FDMS7692A	 FDMS7692E	 FDMS7694
 FDMS7694	 FDMS7696A	 FDMS7698	 FDMS7698	 FDMS7700S
 FDMS7700S	 FDMS8018	 FDMS8018	 FDMS8020	 FDMS8020
 FDMS8023S	 FDMS8023S	 FDMS8025AS	 FDMS8025S	 FDMS8025S
 FDMS8026S	 FDMS8027S	 FDMS8027S	 FDMS8027S	 FDMS8050
 FDMS8050	 FDMS8050ET30	 FDMS8050ET30	 FDMS8320L	 FDMS8320L
 FDMS8322	 FDMS8333L	 FDMS8333L	 FDMS8460	 FDMS8460
 FDMS8460S	 FDMS8558S	 FDMS8558S	 FDMS8558SDC	 FDMS8558SDC
 FDMS8560S	 FDMS8560S	 FDMS8570S	 FDMS8570S	 FDMS86101

Contact us: Info@Y-IC.com

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